

Fast timing possibilities at FCC-ee

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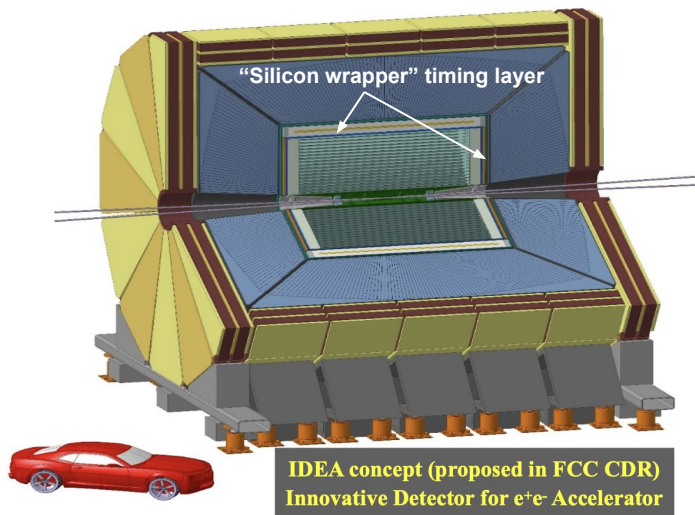
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Introduction

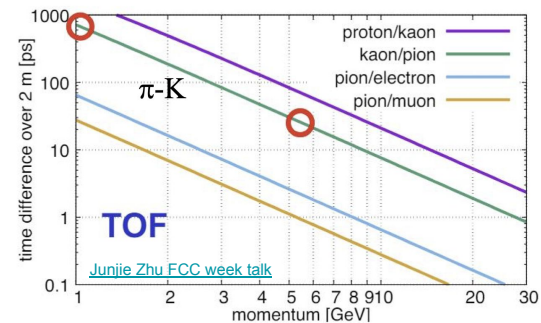
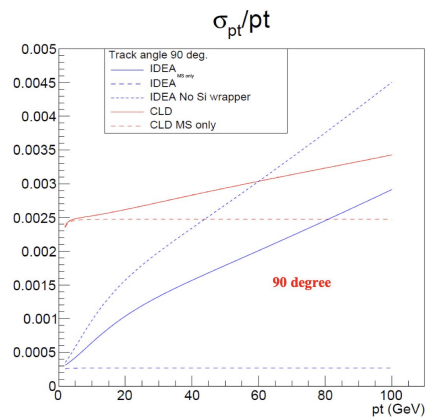
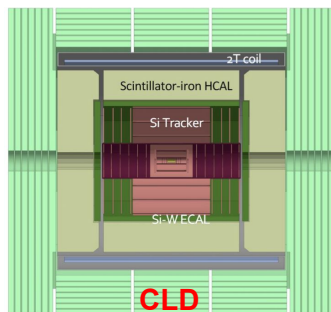
- Topics covered in today's talk:
 - Technologies for 4D tracking
 - LGAD technology
 - AC-LGADs @ EIC
 - Design optimization
 - Front-end readout
 - Monolithic CMOS options



FCC-ee Detector Designs



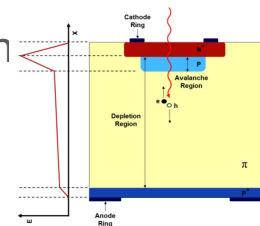
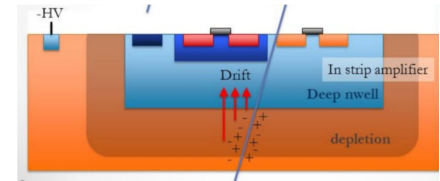
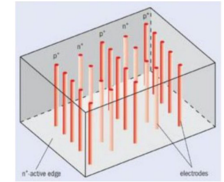
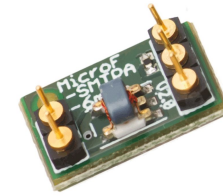
- **Precision silicon layer around the central tracker**
 - Improve momentum resolution
 - Extend tracking coverage in the forward/backward region by providing an additional point to particles with few measurements in the drift chamber
 - Provide a time of flight measurement for particle ID
- **Covered area ~90 m²**
 - Important impact on services
 - Technology suitable for large size production
 - Do not want acceptance holes



Technology for 4D tracking

Which technology has sufficient time resolution for 4D tracking

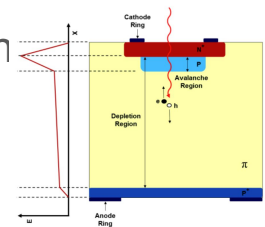
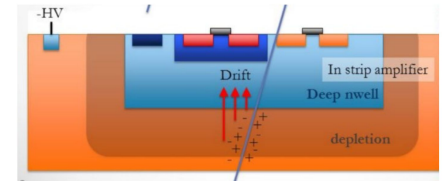
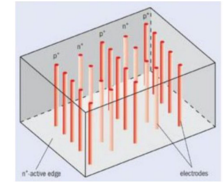
- **SiPM (Silicon photomultiplier)**
 - But very little radiation hardness and low granularity
- **3D silicon sensors**
 - Perpendicular charge collection, ~20-30ps of time resolution, limitations due to dead areas and non-homogeneous field
- **Low Gain Avalanche Detectors (LGADs)**
 - Intrinsic gain, thin bulk, ~20-30ps of time resolution
 - Charge sharing allows spatial resolution <30 um
- **Monolithic CMOS detector**
 - Embedded amplification in the design, ~50-100 ps of time resolution
 - Extremely small pixels possible → excellent spatial resolution
- **In the future: LGAD CMOS? New materials (diamond)?**



Technology for 4D tracking

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“Fast timing”

- An integrated detector with excellent temporal resolution requires **many ingredients**:

- Sensor
 - Technology, bandwidth
 - Power
- ASIC
 - Cabling, module design, sensor biasing, noise rejection, etc ...
- Infrastructure
 - Clock distribution
 - Cooling
 - Data transfer

$$\sigma_t^2 = \sigma_{\text{ionization}}^2 + \sigma_{\text{jitter}}^2 + \sigma_{\text{TDC}}^2 + \sigma_{\text{clock}}^2$$

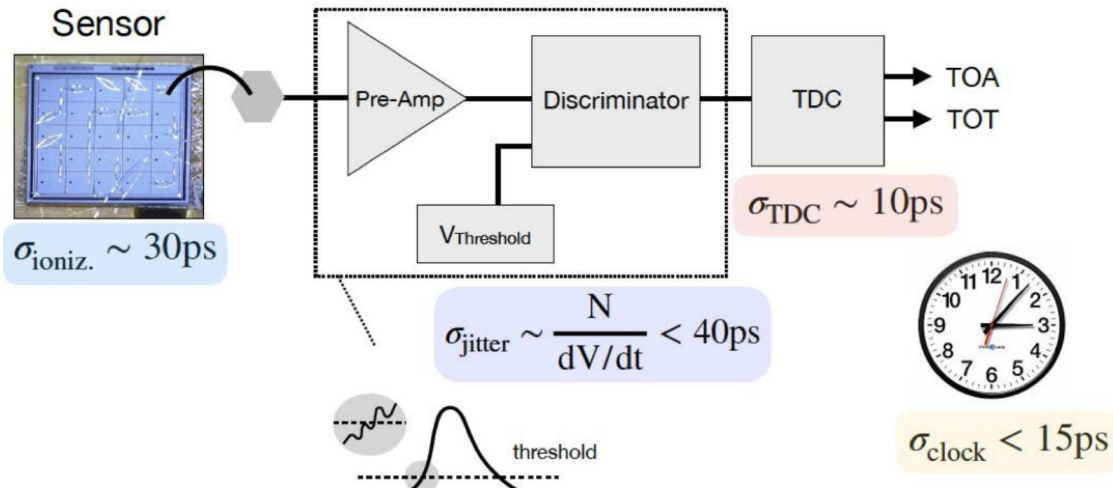


Image credit: Zhenyu Ye

“Fast timing”

Several sources of noise when considering a detector system with excellent temporal resolution:

- $\sigma_{\text{ionization}}$: variations in charge depositions \rightarrow impacts amplitude and shape of the signal
- σ_{jitter} : minimized with low noise electronics and maximizing the slew rate (dV/dt) of the signal
- σ_{TDC} : the effect of TDC binning
- σ_{clock} : contributions from clock distribution

$$\sigma_t^2 = \sigma_{\text{ionization}}^2 + \sigma_{\text{jitter}}^2 + \sigma_{\text{TDC}}^2 + \sigma_{\text{clock}}^2$$

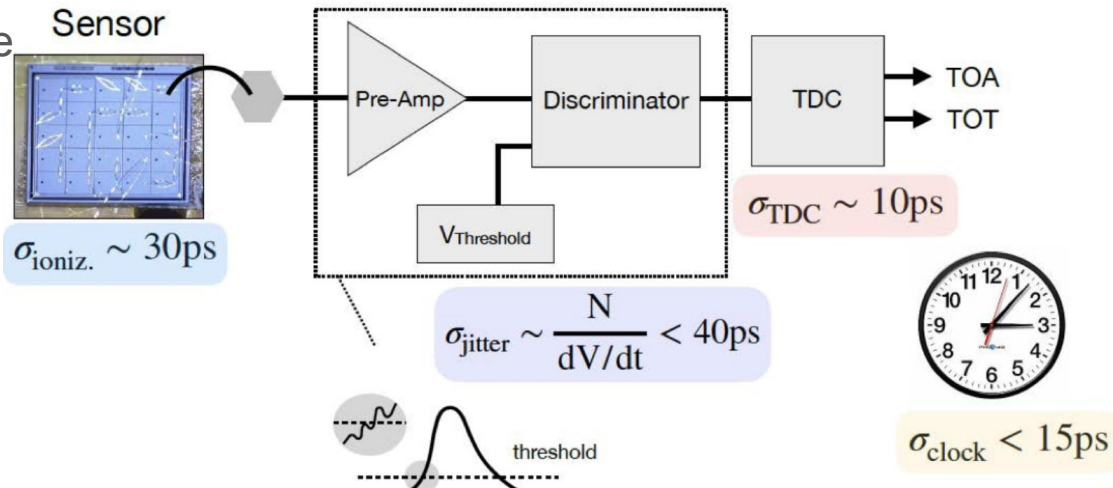
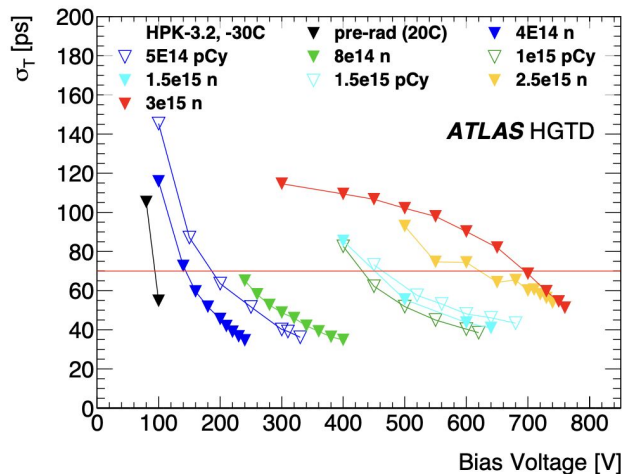
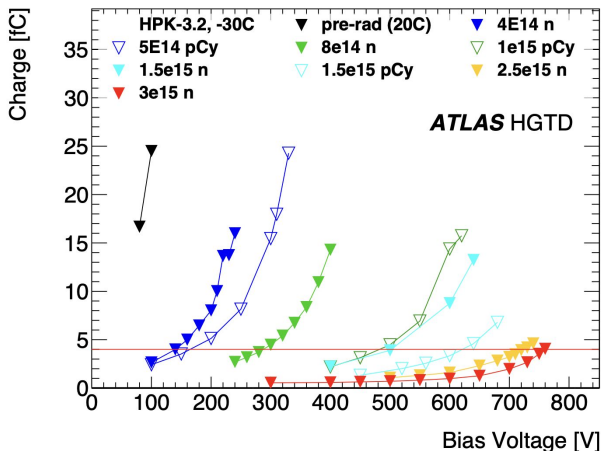
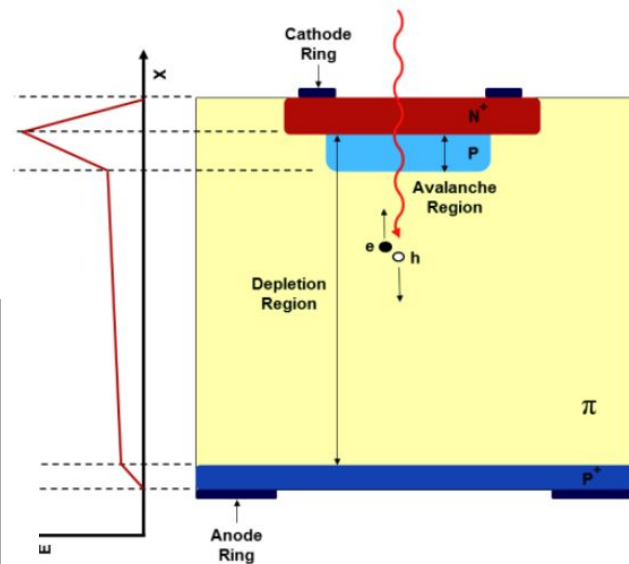


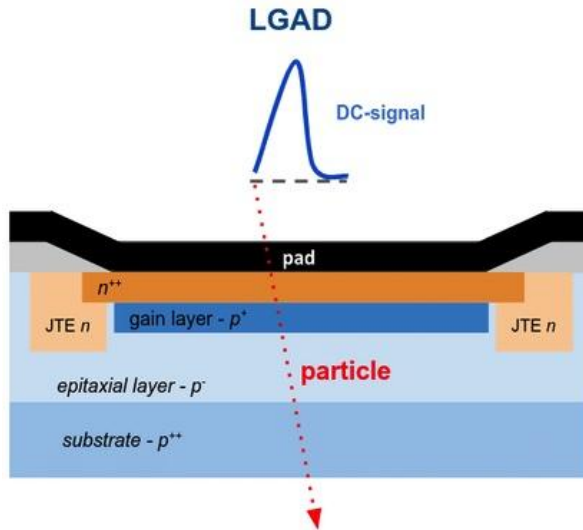
Image credit: Zhenyu Ye

Low Gain Avalanche Detectors

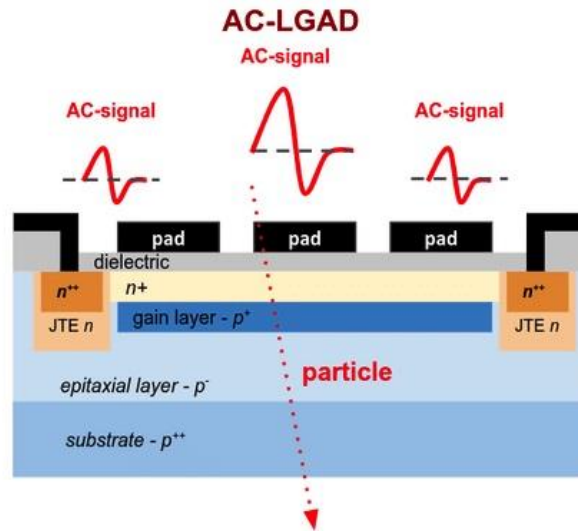
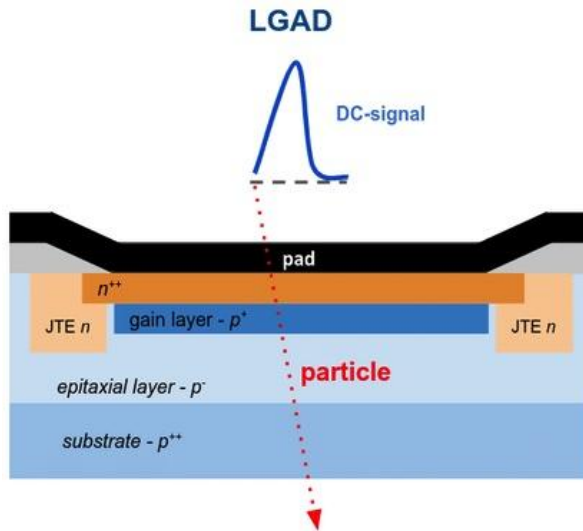
- LGAD: silicon detector with a thin (<5um) and highly doped ($\sim 10^{16}$ P++) multiplication layer
- LGADs have intrinsic modest internal gain (10-50)
 - Not in avalanche mode \rightarrow controlled & tunable gain with externally applied bias voltage
- Excellent timing resolution even for high fluences!



- LGADs have excellent timing resolution, but relatively poor spatial resolution
 - The JTE creates a gap between LGAD pads → 100% fill factors cannot be achieved
 - Position resolution is limited to be $\sqrt{1/12}$ of the pad size
- For FCC-ee, **desire position resolution down to $O(10)$ μm level and 100% fill factor**
 - **Unachievable with traditional DC-LGAD detectors technology**

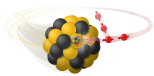


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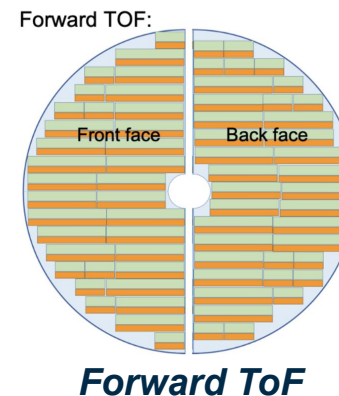
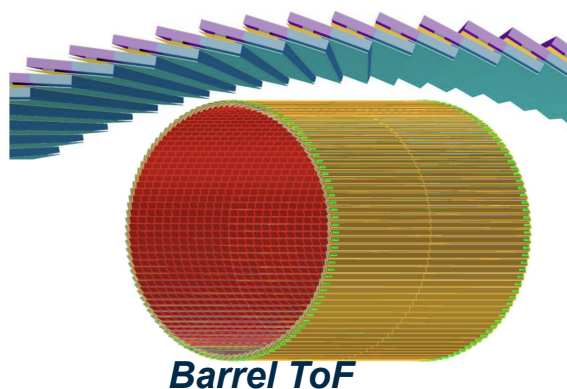
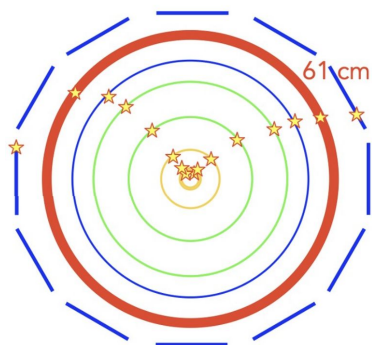
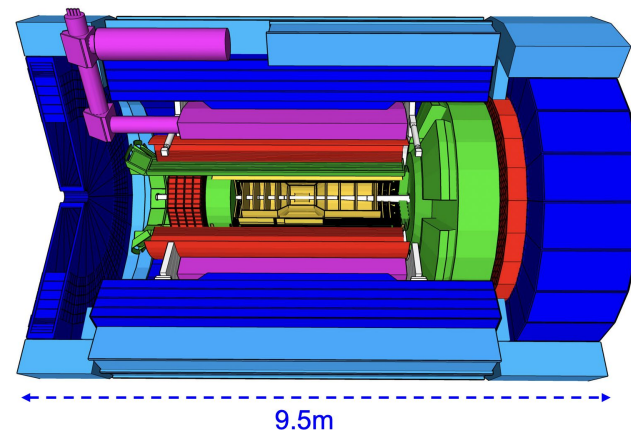


AC-LGAD technology:

- Replace the segmented n^{++} layer with a continuous n^+ layer
- Electrical signals in the n^+ layer are AC coupled to the readout pads/strips, which are separated with a thin dielectric material.
- Charge sharing between strips/pads **significantly improves spatial resolution and maintains temporal resolution!**



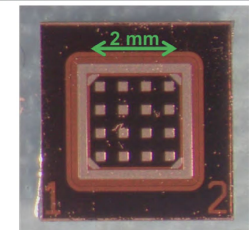
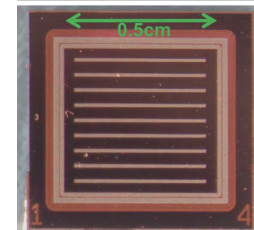
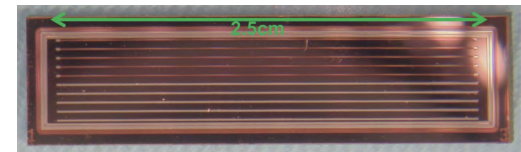
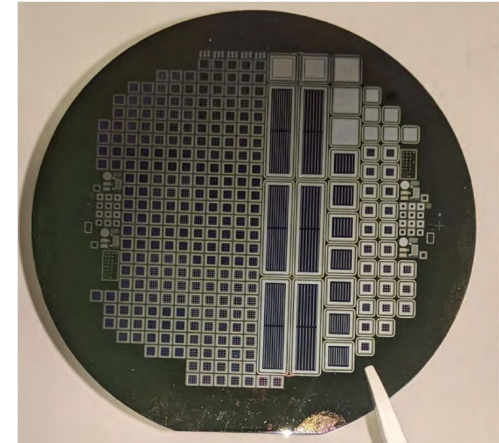
- **Electron Ion Collider will include an AC-LGAD time of flight layer: used in tracking and PID**
- Single AC-LGAD layer: **Barrel (strips) and end-cap (pads) with total area of $\sim 13\text{m}^2$**
- Much of the design & challenges being faced for this project directly transferable! **But, FCC-ee will be almost an order of magnitude larger...!**
- Timing and spatial requirements similar to those that would be needed for FCC-ee



Sensor design optimization

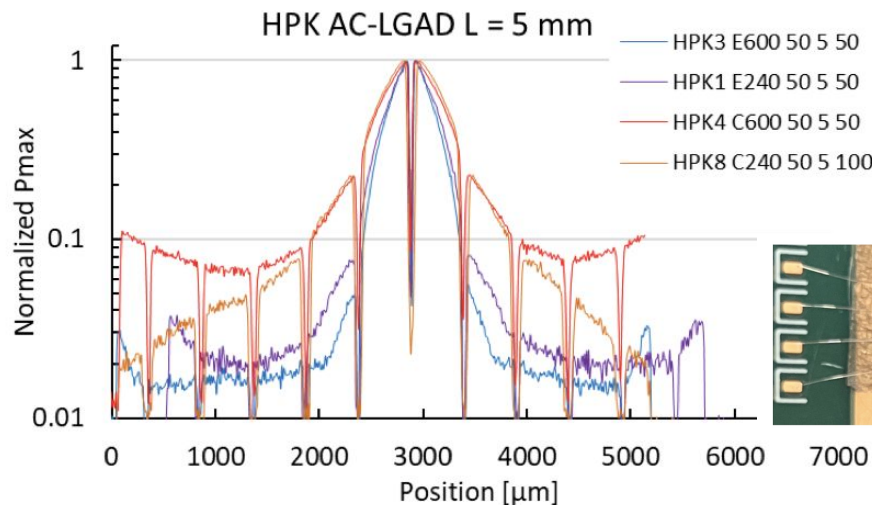
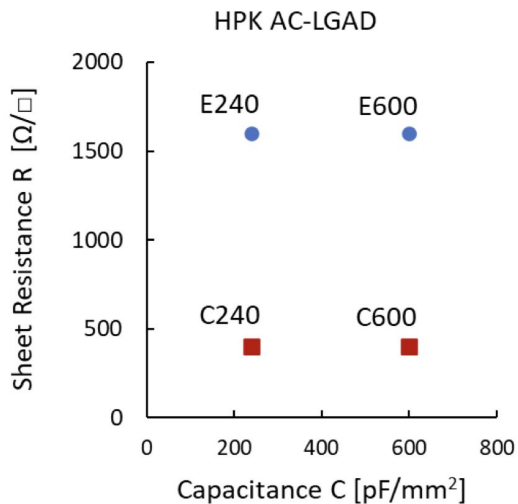
- Strict timing and spatial requirements for all time of flight detectors for ePIC
- Several years of sensor optimization:
 - **BNL**: quick turnaround time, very useful for R&D
 - **HPK**: commercial vendor for large scale production
- **Investigating properties:**
 - **n+ layer** : very important for charge sharing
 - **Strip length/pitch**: minimize channel count → reduces power consumption
 - **Sensor thickness**: aim to improve timing resolution

	Area (m^2)	Time resolution	Spatial resolution	Material budget
Barrel Time-of-Flight	10	35 ps	$30 \mu m$ in $r \cdot \phi$	$0.01 X_0$
Forward Time-of-Flight	2.2	25 ps	$30 \mu m$ in x and y	$0.05 X_0$
B0 Tracker	0.07	30 ps	$20 \mu m$ in x and y	$0.01 X_0$
Roman Pots	0.14	30 ps	$140 \mu m$ in x and y	no strict req.
Off-Momentum Detectors	0.08	30 ps	$140 \mu m$ in x and y	no strict req.

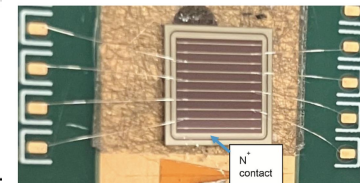


Charge sharing in AC-LGADs

- Charge sharing between neighboring strips is essential for good position resolution
 - However large sharing beyond the next neighbor generates background signals which in general are detrimental to the sensor goal of low occupancy

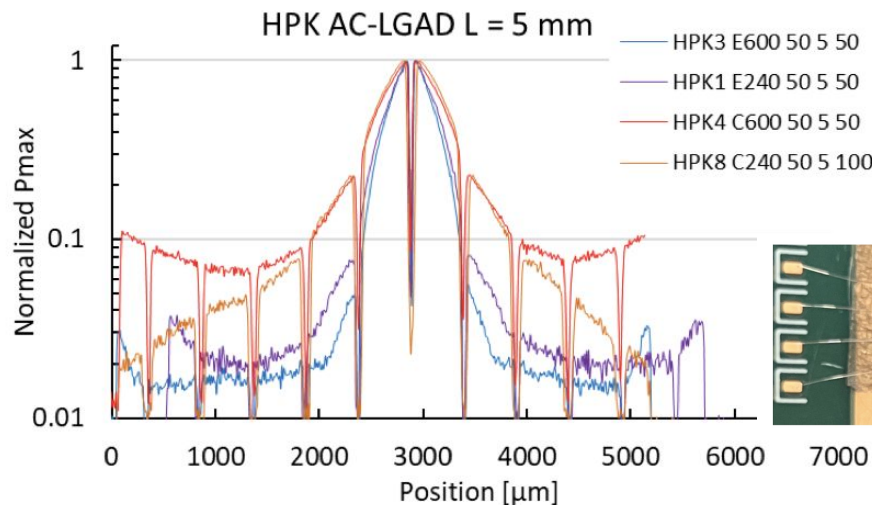
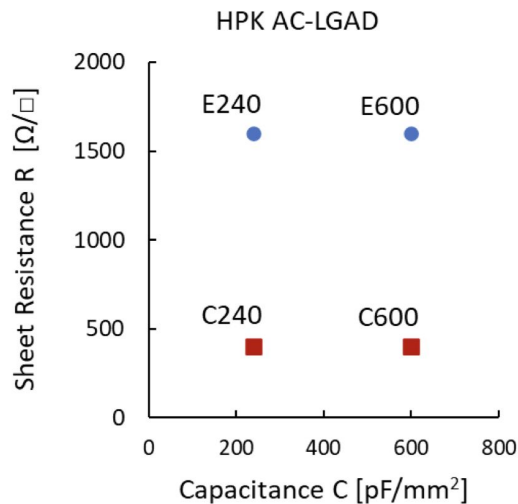


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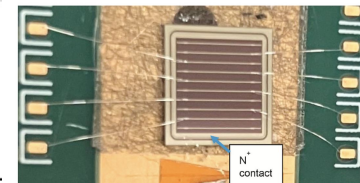


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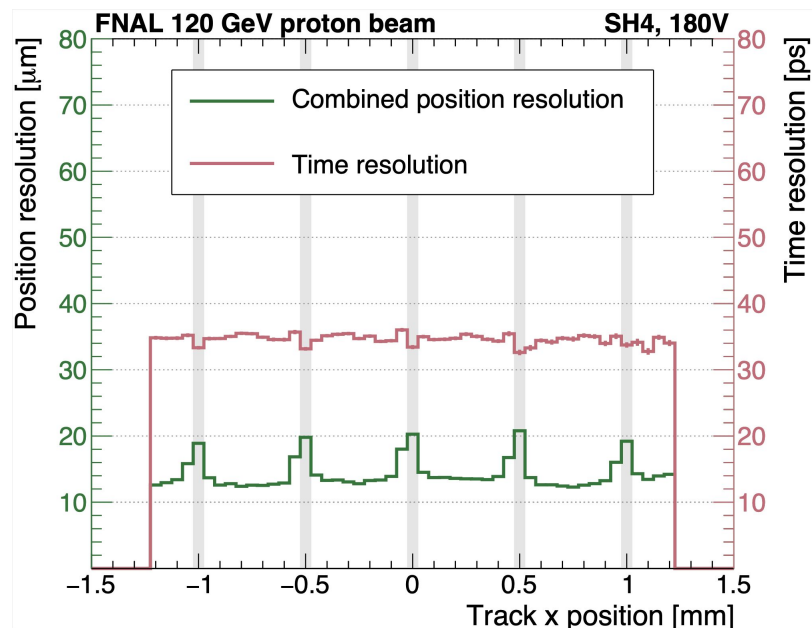
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→ **Sensors with large sheet resistance give best performance with next neighbour charge sharing at the 10-15% level**

Timing & position resolution

- Sensors with different configurations tested with 120 GeV protons @ FNAL

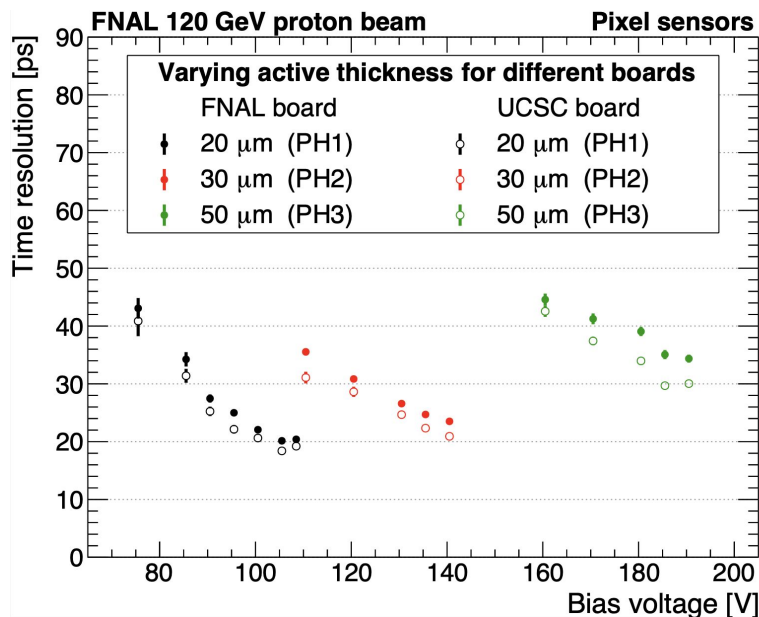
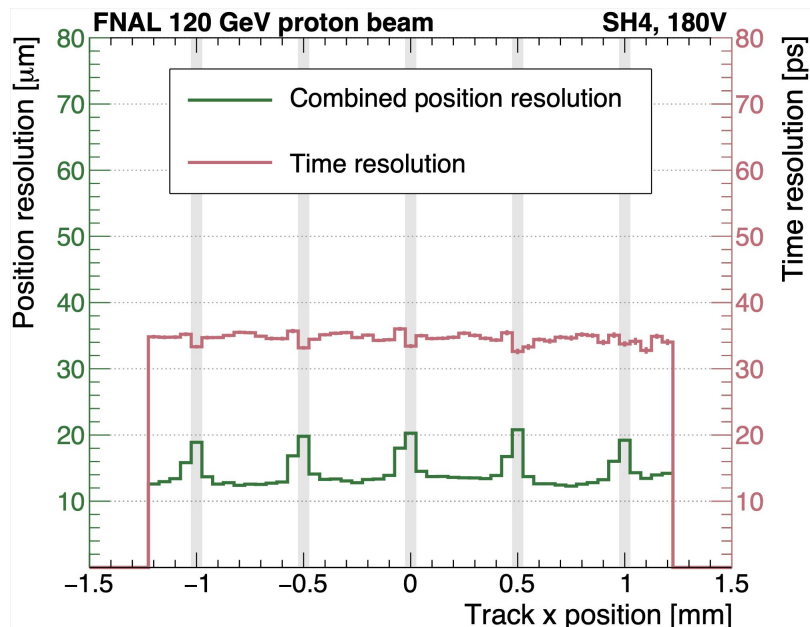


HPK strip sensors with 500 μm pitch:

→ Simultaneously achieving ~15 μm position and ~35 ps timing resolution achieved in one sensor!

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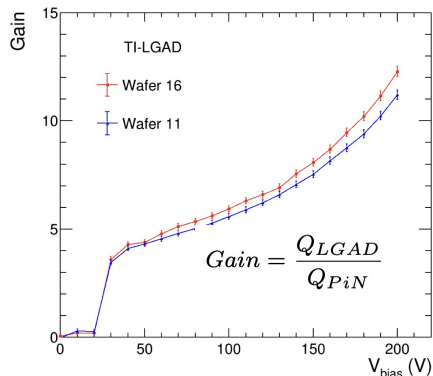
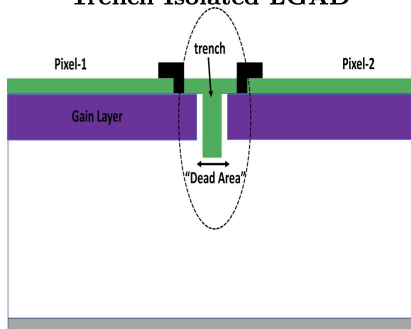
HPK pixel sensors with different thickness:

→ Thinner sensors capable of achieving time resolution down to 20 ps!

Trench insulated LGADs (TI-LGADs)

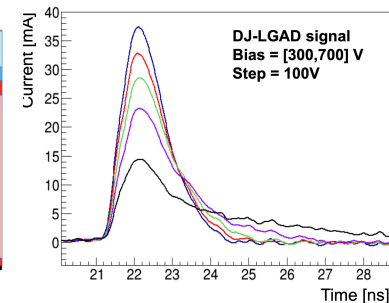
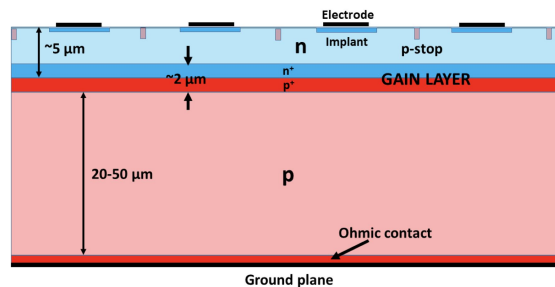
- Replace JTE and p-stop of LGADs with a narrow (<1um) & shallow trench of SiO₂
 - Trenches act as a drift/diffusion barrier
 - Dead regions significantly reduced!
- Several advantages over traditional LGADs: smaller gain-loss region, great timing resolution & improved spatial resolution

Trench Isolated LGAD



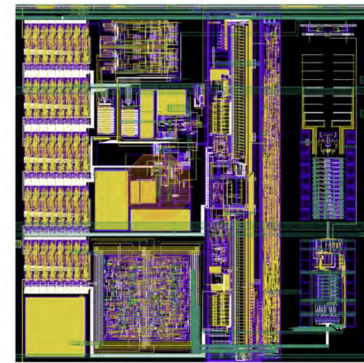
Deep-Junction LGAD (DJ-LGAD)

- Gain layer is buried, so the top can be segmented as in normal silicon detectors
- First production completed by Cactus material in collaboration with BNL and UCSC
- Promising performance (gain of ~5) and good pad insulation (few um IP gap)
- Similar granularity as regular silicon sensors

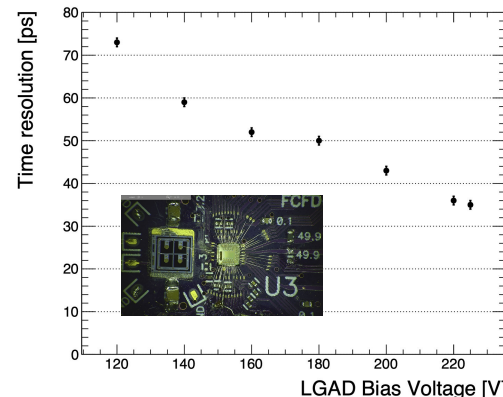


Several ongoing activities:

- **EICROC (Omega/Irfu/AGH)**
 - Aspects based on ALTIROC & HGCRoC from HL-LHC upgrades
 - Designed for low sensor capacitance → planned to readout forward detectors with pixel sensors and be bump-bondable
- **Fermilab Constant Fraction Discriminator ([FCFD](#)):**
 - Constant fraction discriminator (CFD) to measure signal arrival time → robust against amplitude variations of the signal
- **High Timing Precision System on Chip ([HPSoC](#))**
 - Operate with 10 GSa/s waveform digitization, and use autonomous triggering, feature extraction and multichannel data fusion while providing timing precision <10 ps
- **[AS-RoC](#) (SiGe, low power), [FAST](#) (large dynamic range), ...**



EICROC0



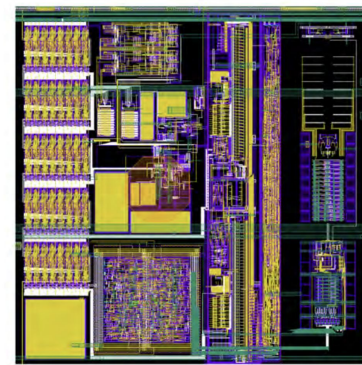
FCFD-V0

Readout ASIC R&D

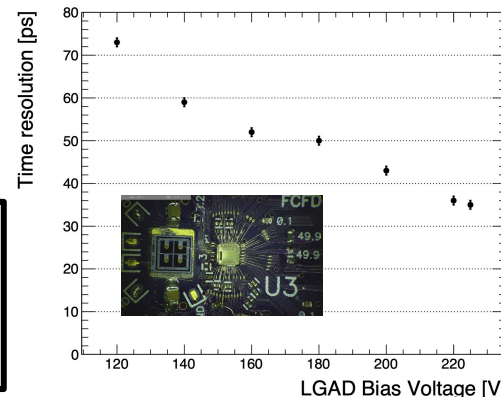
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→ For FCC-ee, prefer **longest possible strips length (i.e. large input capacitance) to reduce number of readout channels, R&D efforts critical to achieve desired timing resolution!**



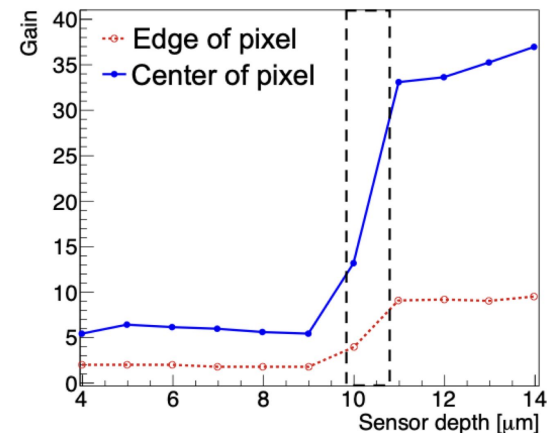
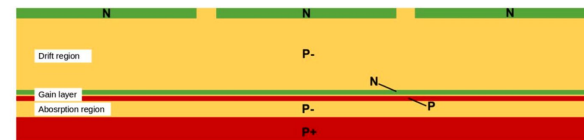
EICROC0



FCFD-V0

HV-CMOS LGADs

- Combination of HV-CMOS technology and LGAD technology
- Internal gain by LGAD-like gain layer and embedded amplification
- Several challenges to overcome:
 - LGAD gain layer has high electric field near the surface, not easy to work with CMOS tech in it
 - LGADs mostly produced on 4" and 6" wafers while CMOS foundries work with 8" wafers
- First successful LGAD CMOS: 130 nm SiGe BiCMOS process by IHP microelectronics [PicoAD](#):
 - Exagonal pads, 65 μm
 - About 25 μm depletion
 - Thinned to 60 μm
 - **Resolution of about ~ 38 ps,**
 - **Very small pixels!**



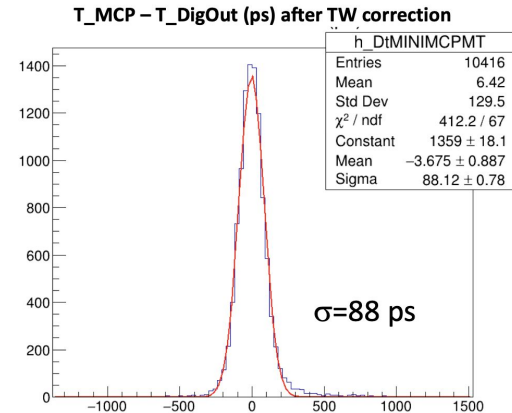
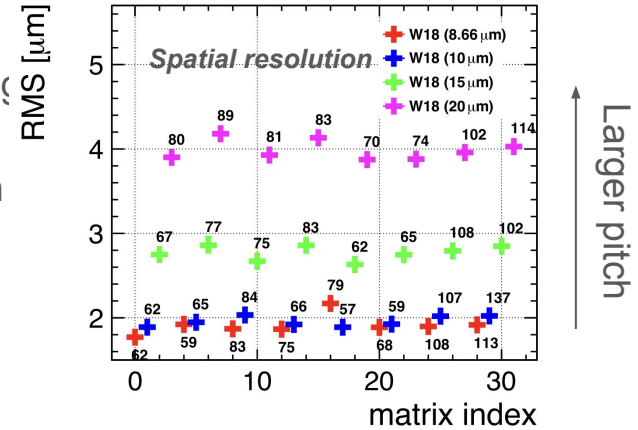
CMOS Sensors without internal gain

FASTPIX is a **180 nm CMOS monolith project** aiming at combining temporal stamping with excellent position precision

- Lateral doping gradient leads to accelerated charge collection times. Optimization underway
- Very small pixels $\sim 8\text{-}20\ \mu\text{m}$ \rightarrow impressive spatial resolution!
- Timing resolution $\sim 100\text{-}200\ \text{ps}$,

MiniCACTUS is a **150 nm CMOS monolith project**

- Front-end mostly optimized for $1\ \text{mm}^2$ pixels with peaking time of $1\text{-}2\ \text{ns}$ @ $1\text{-}2\ \text{pF}$
- Resolution of about $\sim 90\ \text{ps}$,
- Large pixel, $0.5 \times 1\ \text{mm}^2$



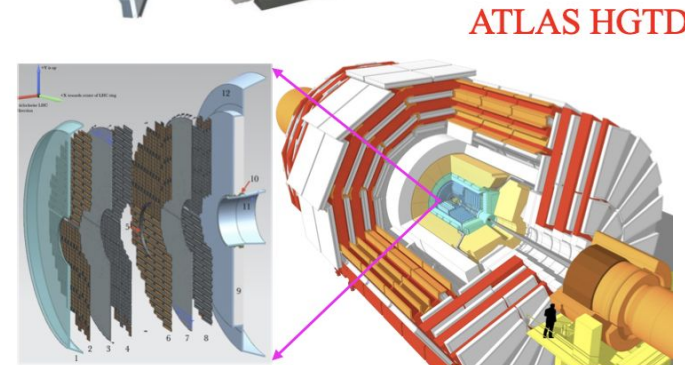
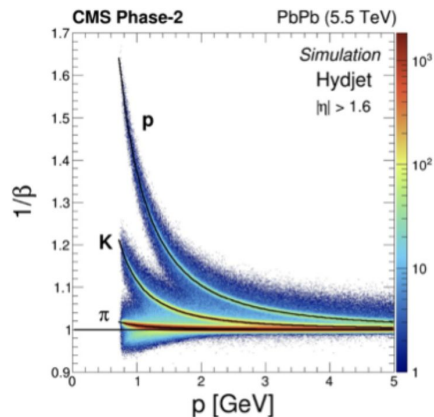
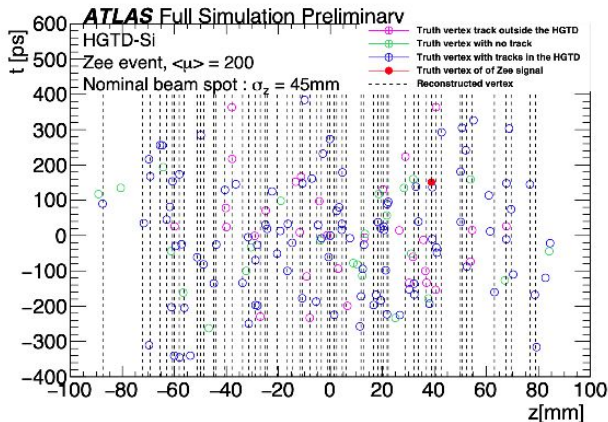
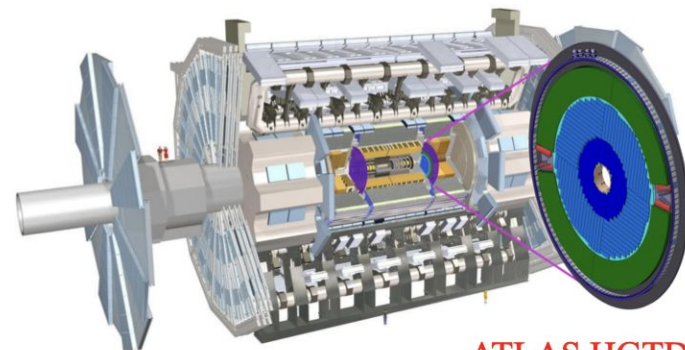
Fast timing detectors are proposed as part of a silicon timing layer at FCC-ee

- LGADs are a promising technology for an all silicon wrapper, capable of providing $O(10)$ ps timing resolution and $<30\mu\text{m}$ spatial resolution
 - Many experiments (e.g. [EIC](#), [PIONEER](#)) in late stages of developing systems that use AC-LGADs → lessons from these experiments useful starting place for FCC-ee!
 - Scaling to FCC will require R&D towards longer strip lengths to reduce channel count, move fabrication to larger wafers to improve yield and reduce costs, etc...
- Fully integrated CMOS systems very promising avenue to explore
 - Capable of extremely small pixels → excellent spatial resolution!
 - Very impressive timing resolutions already achieved

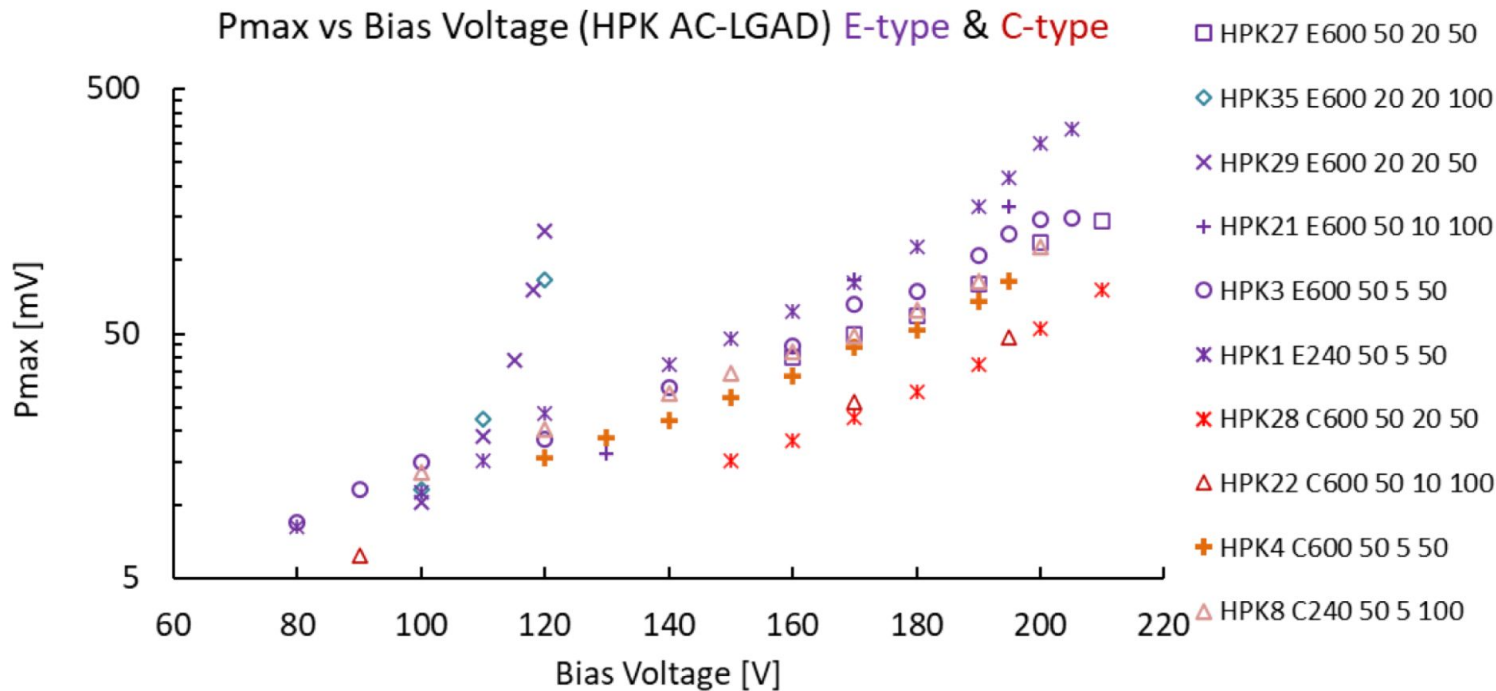
Extra slides

Fast timing @ HL-LHC

- Unprecedented challenges presented by HL-LHC conditions → require innovation and creativity → precision timing!
- ATLAS High-Granularity Timing Detector (HGTD)
 - Sensors pads $1.3 \times 1.3 \text{ mm}^2$
 - Rise time $\sim 500 \text{ ps}$
- Extremely useful in dense environments, PID, ...



Pmax for various HPK sensors



- Hexagonal pixels – large signal-to-noise ratios, high detection efficiency and **precise timing**
- Minimizing the maximum distance between charge generation and collection is a first step in the optimization for timing uniformity and is realized by the hexagonal arrangement of collection electrodes and the $O(10\mu\text{m})$ pixel pitch.
 - With the modified process, a uniform low-dose n-type implant is introduced allowing full lateral depletion of the $25\ \mu\text{m}$ epitaxial layer.

